Electronic Supplementary Information

Correlation between native defects and dopants in colloidal lanthanide-doped Ga₂O₃ nanocrystals: A path to enhancing functionality and controlling optical properties

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Fig. S1 TEM images (left) and size distribution histograms (right) of Eu^{3+} -doped Ga_2O_3 NCs with an average Eu^{3+} doping concentration of: (a) 0.07%, (b) 0.8%, (c) 3.9%, and (d) 7.4%.

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Fig. S2 Steady-state PL spectra of highly Eu^{3+} -doped (3.9 and 7.4 % doping concentrations) Ga_2O_3 NCs. Eu^{3+} intra-4f transitions are readily observed even in steady-state spectra.



Fig. S3 Typical electronic absorption spectrum of Eu^{3+} in an aqueous solution. The arrow indicates ${}^{7}F_{0} \rightarrow {}^{5}L_{6}$ transition used for direct excitation of Eu^{3+} .

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Fig. S4 Time-gated PL spectrum of 10 % Tb^{3+} -doped Ga₂O₃ NCs, showing the assignment of the observed f-f transitions.



Fig. S5 Photographs of γ -Ga₂O₃ (left), 7.4 % Eu³⁺-doped Ga₂O₃ (middle), and 10 % Tb³⁺-doped Ga₂O₃ NC powders (right). Top and bottom panels compare the day-light photographs of isolated samples (top), and the same samples illuminated with 250 nm UV light (bottom). The luminescence can be clearly observed even in day light.

Eu^{3+} doping conc. (%)	half-life (µs)	
0	5.67	
0.04	5.18	
0.07	4.70	
0.2	4.55	
0.5	4.05	

Table S1. Half-life of the DAP emission of Eu^{3+} -doped γ -Ga₂O₃ NCs for different doping concentrations.

Table S2. CIE color coordinates (*x*, *y*) of 0.07 % Eu³⁺-doped γ -Ga₂O₃ NCs for varying delay times calculated from the PL spectra in Fig. 8a.

delay time (ms)	x	У
0 (steady-state)	0.210	0.268
0.1	0.274	0.335
0.3	0.338	0.337
0.5	0.385	0.341
0.7	0.414	0.345
1.1	0.451	0.349
1.7	0.475	0.352